

Surface Mount Rectifier Diode

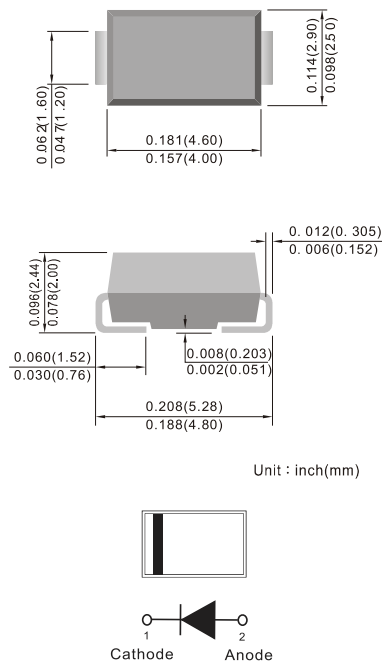
Features

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

Mechanical Data

- **Case:** DO-214AC (SMA)
Molding compound, UL flammability classification rating 94V-0
Moisture sensitivity level: level 1, per J-STD-020
- **Terminal:** Matte tin plated leads, solderable per JESD22-B102
Meet JESD 201 class 2 whisker test
- **Polarity:** Indicated by cathode band
- **Weight:** 0.06 g (approximately)

DO-214AC (SMA)



Maximum Ratings and Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	M1	M2	M3	M4	M5	M6	M7	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I _{F(AV)}	1							A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30							A
Maximum instantaneous forward voltage (Note 1) @ 1 A	V _F	1.1							V
Maximum reverse current @ rated V _R T _J =25°C T _J =125°C	I _R	5 50							μA
Typical reverse recovery time (Note 2)	t _{rr}	2.0							μs
Typical junction capacitance (Note 3)	C _J	12							pF
Non-repetitive peak reverse avalanche energy at 25°C, I _{AS} =1A, L=10mH	E _{RSM}	5							mJ
Typical thermal resistance	R _{θJL} R _{θJA}	27 75					30 85		°C/W
Operating junction temperature range	T _J	- 55 to +150							°C
Storage temperature range	T _{STG}	- 55 to +150							°C

Note:

1. Pulse test with PW=300μs, 1% duty cycle
2. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
3. Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

Characteristics Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

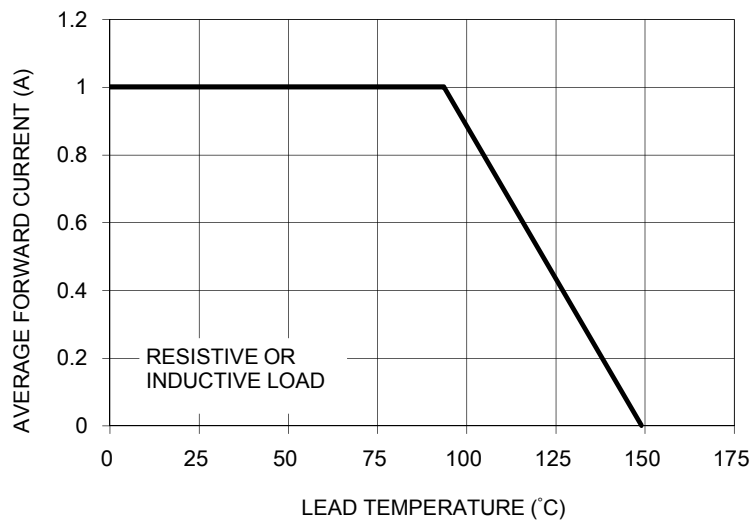


FIG. 2 TYPICAL REVERSE CHARACTERISTICS

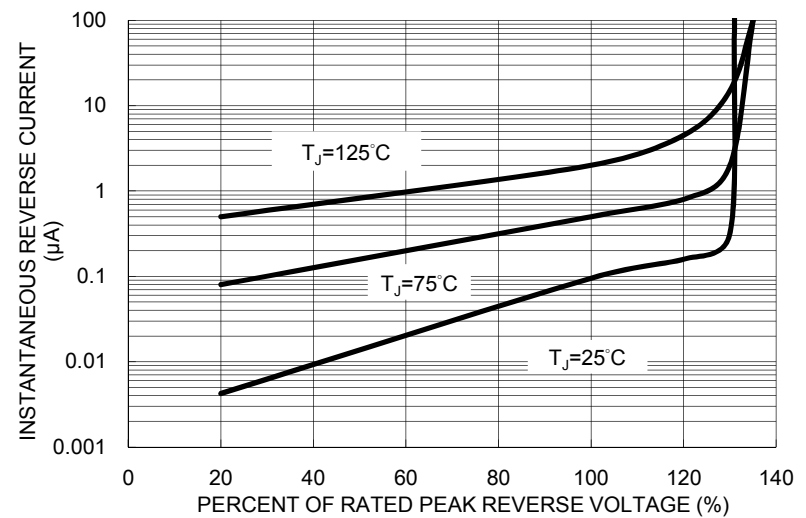


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

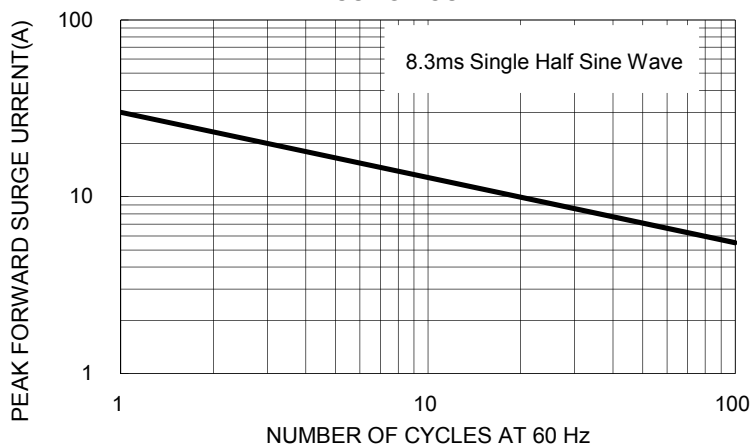


FIG. 4 TYPICAL FORWARD CHARACTERISTICS

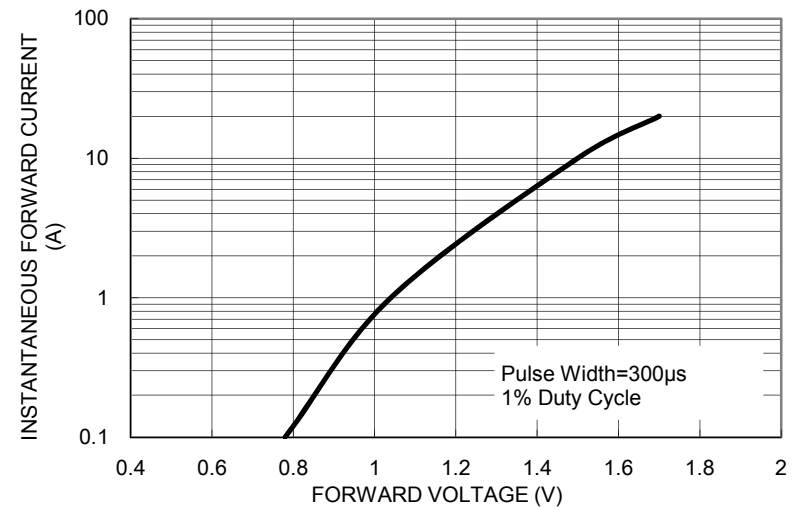


FIG. 5 TYPICAL JUNCTION CAPACITANCE

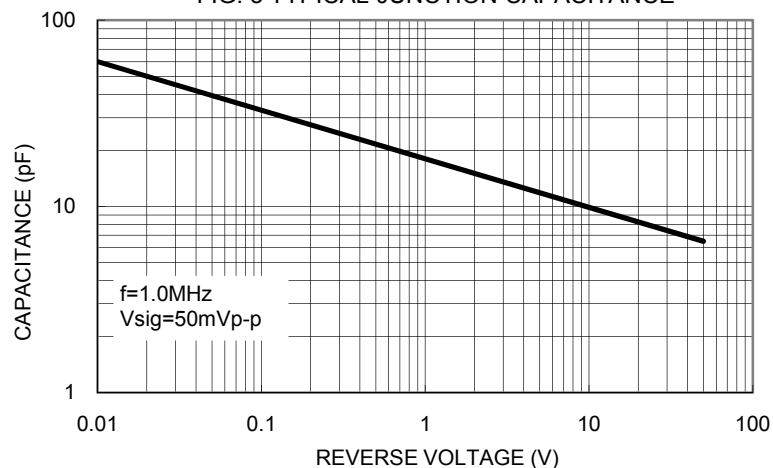


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

